

# SANYO Semiconductors DATA SHEET

# 2SK3833 — General-Purpose Switching Device Applications

#### **Features**

- Low ON-resistance.
- Ultrahigh-speed switching.
- 4V drive.
- Motor drive, DC / DC Converter.
- · Avalanche resistance guarantee.

### **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		100	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		48	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	192	Α
Allowable Power Dissipation	D-		2.5	W
	PD	Tc=25°C	85	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C
Avalanche Energy (Single Pulse) *1	EAS		144	mJ
Avalanche Current *2	IAV		48	Α

<sup>\*1.</sup> V<sub>DD</sub>=20V, L=100μH, I<sub>AV</sub>=48A

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			1.114
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	100			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =100V, V <sub>GS</sub> =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> = ±16V, V <sub>DS</sub> =0			±10	μΑ
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =24A	20	33		S
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)1	I <sub>D</sub> =24A, V <sub>GS</sub> =10V		26	34	mΩ
	R <sub>DS</sub> (on)2	ID=24A, VGS=4V		31	43	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> =20V, f=1MHz		4200		pF
Output Capacitance	Coss	V <sub>DS</sub> =20V, f=1MHz		300		pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =20V, f=1MHz		250		pF

Marking: K3833 Continued on next page.

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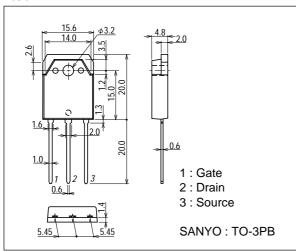
<sup>\*2.</sup> L≤100μH, 1 Pulse

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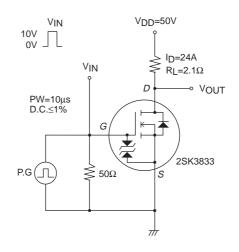
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.		30		ns
Rise Time	t <sub>r</sub>	See specified Test Circuit.		72		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit.		285		ns
Fall Time	tf	See specified Test Circuit.		105		ns
Total Gate Charge	Qg	V <sub>DS</sub> =50V, V <sub>GS</sub> =10V, I <sub>D</sub> =48A		79		nC
Gate-to-Source Charge	Qgs	VDS=50V, VGS=10V, ID=48A		14		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =50V, V <sub>GS</sub> =10V, I <sub>D</sub> =48A		18		nC
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =48A, V <sub>GS</sub> =0		1.04	1.5	V

## **Package Dimensions**

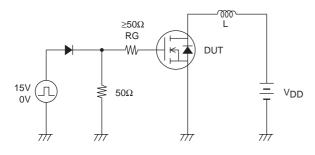
unit : mm 2056A

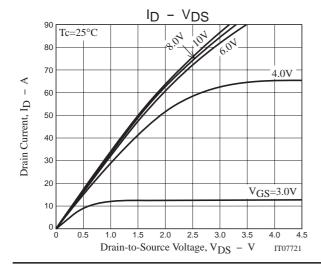


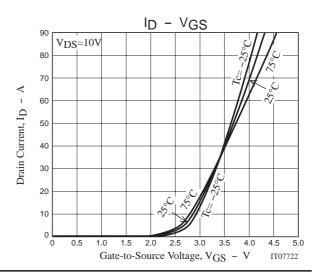
# **Switching Time Test Circuit**

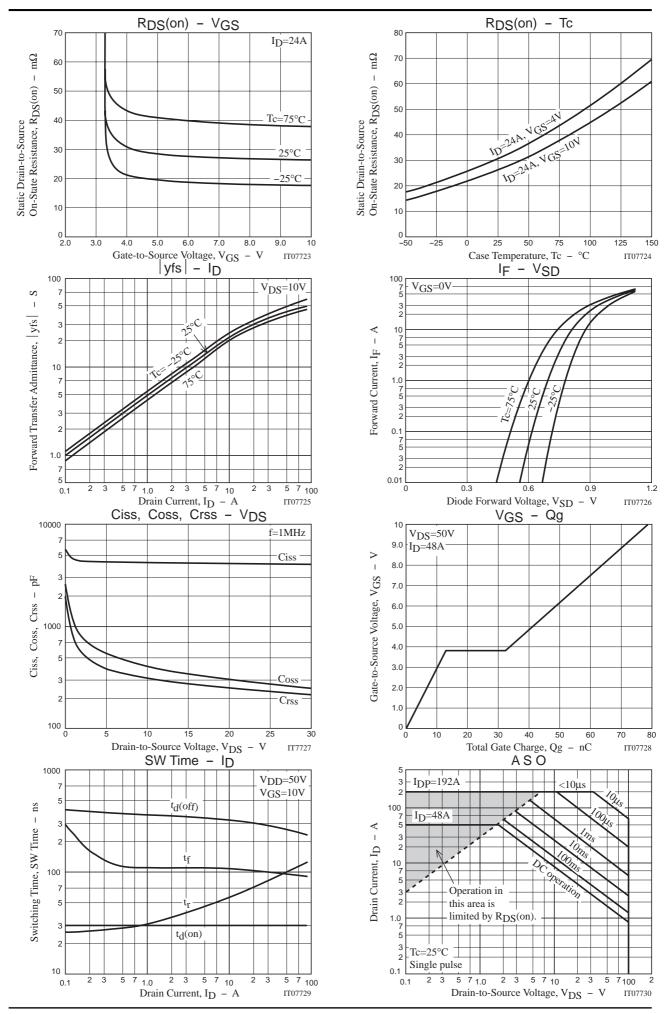


# **Unclamped Inductive Circuit**

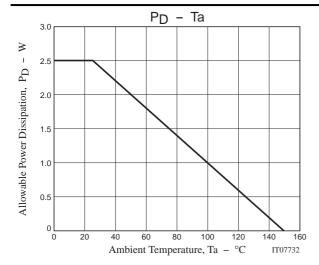


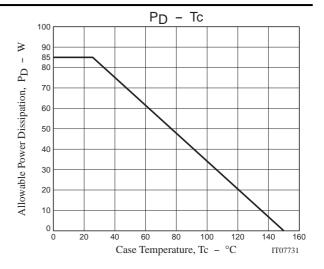






#### 2SK3833





Note on usage : Since the 2SK3833 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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